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AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application:

LISTING OF CLAIMS:

Claims 1. – 55. (canceled)

56. (currently amended): A method of fabricating thin film transistors, comprising:
forming at least one semi-conductive film on a substrate;
immersing said substrate in a dopant; and
independently tilting a plurality of tiltable beam steering elements to deliver ~~delivering~~ a laser beam to a plurality of independently selectable location on said substrate ~~with a plurality of independently tiltable beam steering elements~~ to induce a doping reaction between said dopant and said semi-conductive film at said independently selectable locations.

57. (previously presented): The method claimed in claim 56, wherein said semi-conductive film comprises a semiconductor film..

58. (previously presented): The method claimed in claim 56, wherein said semi-conductive film comprises silicon.

59. (previously presented): The method claimed in claim 58, wherein said semi-conductive film is deposited on an insulating substrate.

60. (original): The method claimed in claim 59 and wherein said insulating substrate comprises glass.